Single-Channel, Rail-to-Rail Output, 3 MHz BW Operational Amplifier

The TLV271 operational amplifier provides rail–to–rail output operation. The output can swing within 320 mV to the positive rail and 50 mV to the negative rail. This rail–to–rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3 MHz bandwidth. The TLV271 can operate on supply voltage as low as 2.7 V over the temperature range of –40°C to 105°C. The high bandwidth provides a slew rate of 2.4 V/ μ s while only consuming 550 μ A of quiescent current. Likewise the TLV271 can run on a supply voltage as high as 16 V making it ideal for a broad range of battery–operated applications. Since this is a CMOS device it has high input impedance and low bias currents making it ideal for interfacing to a wide variety of signal sensors. In addition it comes in a small TSOP–5 package with two pinout styles allowing for use in high–density PCB's.

Features

• Rail-To-Rail Output

Wide Bandwidth: 3 MHz
High Slew Rate: 2.4 V/µs

• Wide Power-Supply Range: 2.7 V to 16 V

Low Supply Current: 550 μA
Low Input Bias Current: 1 pA

• Wide Temperature Range: -40°C to 105°C

• Small Package: 5 Pin TSOP-5 (same as SOT23-5)

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

1

Applications

- Notebook Computers
- Portable Instruments



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MARKING DIAGRAM



TSOP-5 (SOT23-5) SN SUFFIX CASE 483

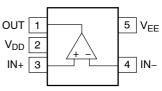


A = Assembly Location

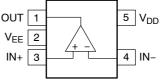
Y = Year W = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



Style 1 Pinout (SN1T1) (Top View)



Style 2 Pinout (SN2T1) (Top View)

ORDERING INFORMATION

Device	Package	Shipping [†]
TLV271SN1T1G	TSOP-5	3000 /
(Style 1 Pinout)	(Pb-Free)	Tape & Reel
TLV271SN2T1G	TSOP-5	3000 /
(Style 2 Pinout)	(Pb-Free)	Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V_{DD}	Supply Voltage (Note 1)	16.5	V
V_{ID}	Input Differential Voltage (Note 2)	± Supply Voltage	V
VI	Input Common Mode Voltage Range (Note 1)	-0.2 V to (V _{DD} + 0.2 V)	V
I _I	Maximum Input Current	±10	mA
Io	Output Current Range	±100	mA
	Continuous Total Power Dissipation (Note 1)	200	mW
TJ	Maximum Junction Temperature	150	°C
$\theta_{\sf JA}$	Thermal Resistance	333	°C/W
T _{stg}	T _{stg} Operating Temperature Range (free-air)		°C
T _{stg}	Storage Temperature	-65 to 150	°C
	Mounting Temperature (Infrared or Convection – 20 sec)	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.7V, 3.3V, 5V & \pm 5 V (Note 3), T_A = 25°C, R_L \geq 10 k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	VIC = $V_{DD}/2$, V_{O} = $V_{DD}/2$, R_{L} = 10 k Ω , R_{S} = 50 Ω			0.5	5	mV
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				7	
Offset Voltage Drift	ICV _{OS}	VIC = $V_{DD}/2$, $V_{O} = V_{DD}/2$, $R_{L} = 10 \text{ k}\Omega$, R_{S}	= 50 Ω		2		μV/°C
Common Mode	CMRR	$0 \text{ V} \leq \text{VIC} \leq \text{V}_{DD} - 1.35 \text{ V}, \text{R}_{S} = 50 \Omega$	V _{DD} = 2.7 V	58	70		dB
Rejection Ratio		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		55			
		$0 \text{ V} \leq \text{VIC} \leq \text{V}_{DD} - 1.35 \text{ V}, \text{R}_{S} = 50 \Omega$	V _{DD} = 5 V	65	80		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$	1	62			
		$0 \text{ V} \leq \text{VIC} \leq \text{V}_{DD} - 1.35 \text{ V}, \text{R}_{S} = 50 \Omega$	$V_{DD} = \pm 5 \text{ V}$	69	85		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		66			
Power Supply	PSRR	V_{DD} = 2.7 V to 16 V, VIC = V_{DD} /2, No Loa	d	70	80		dB
Rejection Ratio		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		65			
Large Signal	A_{VD}	$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	V _{DD} = 2.7 V	97	106		dB
Voltage Gain		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$	1	76			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	V _{DD} = 3.3 V	97	115		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$	1	76			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	V _{DD} = 5 V	100	110		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$	1	86			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	$V_{DD} = \pm 5 \text{ V}$	100	115		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		90			
Input Bias Current			T _A = 25°C		1	150	pА
		$R_S = 50 \Omega$	T _A = 105°C			1000	

^{3.} V_{DD} = ± 5 V is shorthand for V_{DD} = +5 V and V_{EE} = -5 V.

Continuous short—circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

^{2.} ESD data available upon request.

DC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.7V, 3.3V, 5V & ± 5 V (Note 3), T_A = 25°C, R_L \geq 10 k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Input Offset Current	I _{IO}	$V_{DD} = 5 \text{ V}, \text{ VIC} = V_{DD}/2, V_{O} = V_{DD}/2,$	T _A = 25°C		1	150	pА
		$R_S = 50 \Omega$	T _A = 105°C			1000	
Differential Input Resistance	r _{i(d)}				1000		GΩ
Common-mode Input Capacitance	C _{IC}	f = 21 kHz			8		pF
Output Swing	V _{OH}	$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	V _{DD} = 2.7 V	2.55	2.58		V
(High-level)		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		2.48			
		$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	V _{DD} = 3.3 V	3.15	3.21		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		3.00			
		$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	V _{DD} = 5 V	4.8	4.93		
		T _A = -40°C to +105°C		4.75			
		$VIC = V_{DD}/2, I_{OH} = -1 \text{ mA}$	$V_{DD} = \pm 5 V$	4.92	4.96		
		T _A = -40°C to +105°C		4.9			
		$VIC = V_{DD}/2, I_{OH} = -5 \text{ mA}$	V _{DD} = 2.7 V	1.9	2.1		V
		T _A = -40°C to +105°C		1.5			
		$VIC = V_{DD}/2, I_{OH} = -5 \text{ mA}$	V _{DD} = 3.3 V	2.5	2.89		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		2.1			
		VIC = V _{DD} /2, I _{OH} = -5 mA	V _{DD} = 5 V	4.5	4.68		
		$T_A = -40^{\circ}C \text{ to } +105^{\circ}C$		4.35			
		$VIC = V_{DD}/2, I_{OH} = -5 \text{ mA}$	V _{DD} = ±5 V	4.7	4.84		
		$T_A = -40^{\circ}C \text{ to } +105^{\circ}C$		4.65			
Output Swing	V _{OL}	$VIC = V_{DD}/2$, $I_{OL} = -1$ mA	V _{DD} = 2.7 V		0.1	0.15	V
(Low-level)		$T_A = -40^{\circ}C \text{ to } +105^{\circ}C$				0.22	
		$VIC = V_{DD}/2, I_{OL} = -1 \text{ mA}$	V _{DD} = 3.3 V		0.03	0.15	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				0.22	
		$VIC = V_{DD}/2, I_{OL} = -1 \text{ mA}$	V _{DD} = 5 V		0.05	0.1	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				0.15	
		$VIC = V_{DD}/2, I_{OL} = -1 \text{ mA}$	V _{DD} = ±5 V		-4.95	-4.92	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				-4.9	
		$VIC = V_{DD}/2, I_{OL} = -5 \text{ mA}$	V _{DD} = 2.7 V		0.5	0.7	V
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				1.1	
		$VIC = V_{DD}/2, I_{OL} = -5 \text{ mA}$	V _{DD} = 3.3 V		0.13	0.7	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				1.1	
		$VIC = V_{DD}/2, I_{OL} = -5 \text{ mA}$	V _{DD} = 5 V		0.28	0.4	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				0.5	
		VIC = V _{DD} /2, I _{OL} = -5 mA	V _{DD} = ±5 V		-4.84	-4.7	
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$				-4.65	

^{3.} $V_{DD} = \pm 5 \text{ V}$ is shorthand for $V_{DD} = +5 \text{ V}$ and $V_{EE} = -5 \text{ V}$.

DC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.7V, 3.3V, 5V & ± 5 V (Note 3), T_A = 25°C, $R_L \ge 10$ k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Output Current	I _O	$V_O = 0.5 \text{ V from rail}, V_{DD} = 2.7 \text{ V}$	Positive rail		4		mA
			Negative rail		5		
		$V_O = 0.5 \text{ V from rail}, V_{DD} = 5 \text{ V}$	Positive rail		7		
			Negative rail		8		
		$V_O = 0.5 \text{ V from rail}, V_{DD} = 10 \text{ V}$	Positive rail		13		
			Negative rail		12		
Power Supply	I _{DD}	$V_O = V_{DD}/2$	V _{DD} = 2.7 V		470	560	μА
Quiescent Current			V _{DD} = 3.3 V		475	620	
			V _{DD} = 5 V		480	660	
			V _{DD} = 10 V		490	800	
		$T_A = -40$ °C to +105°C				1000	

^{3.} V_{DD} = ± 5 V is shorthand for V_{DD} = + 5 V and V_{EE} = - 5 V.

AC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.7 V, 5 V, & ± 5 V (Note 4), T_A = 25°C, and R_L \geq 10 k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Unity Gain Bandwidth	UGBW	$R_L = 2 \text{ k}\Omega, C_L = 10 \text{ pF}$	V _{DD} = 2.7 V		2.4		MHz
bandwidin			V _{DD} = 5 V to 10 V		3		
Slew Rate at Unity	SR	$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	V _{DD} = 2.7 V	1.35	2.1		V/μS
Gain		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		1			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	V _{DD} = 5 V	1.45	2.4		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		1.2			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	$V_{DD} = \pm 5 \text{ V}$	1.8	2.6		
		$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$		1.3			
Phase Margin	θ_{m}	$R_L = 2 \text{ k}\Omega, C_L = 10 \text{ pF}$			65		0
Gain Margin		$R_L = 2 \text{ k}\Omega$, $C_L = 10 \text{ pF}$			18		dB
Settling Time to 0.1%	t _S	V -step(pp) = 1 V, AV = -1, R_L = 2 k Ω , C_L = 10 pF	V _{DD} = 2.7 V		2.9		μS
		V -step(pp) = 1 V, AV = -1, R _L = 2 kΩ, C_L = 47 pF	V _{DD} = 5 V, ± 5 V		2		
Total Harmonic	THD+N	f = 10 kHz	AV = 1		0.02		%
Distortion plus Noise			AV = 10		0.05		1
			AV = 100		0.18		1
		V_{DD} = 5 V, \pm 5 V, $V_{O(pp)}$ = $V_{DD}/2$, R_L = 2 k Ω , f = 10 kHz	AV = 1		0.02		
			AV = 10		0.09		
			AV = 100		0.5		
Input-Referred	e _n	f = 1 kHz			39		nV/√ Hz
Voltage Noise		f = 10 kHz			35		
Input-Referred Current Noise	i _n	f = 1 kHz			0.6		fA/√Hz

^{4.} $V_{DD} = \pm 5 \text{ V}$ is shorthand for $V_{DD} = +5 \text{ V}$ and $V_{EE} = -5 \text{ V}$.

APPLICATIONS

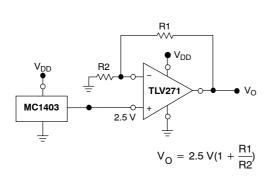


Figure 1. Voltage Reference

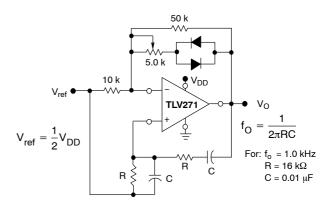


Figure 2. Wien Bridge Oscillator

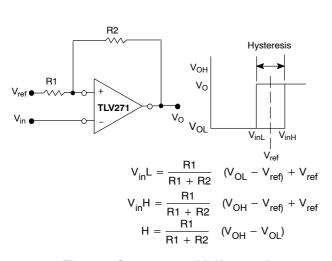
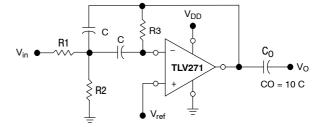


Figure 3. Comparator with Hysteresis



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value
$$f_o$$
, $\frac{C}{Q}$
Then: $R3 = \frac{Q}{\pi f_O C}$
$$R1 = \frac{R3}{2 \text{ A}(f_O)}$$

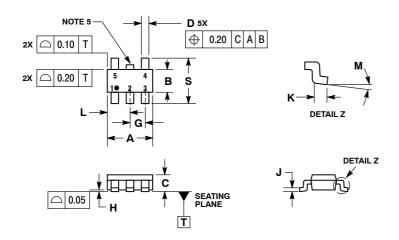
$$R2 = \frac{R1 \text{ R3}}{4Q^2 \text{ R1} - R3}$$

For less than 10% error from operational amplifier, (($Q_O f_O$)/BW) < 0.1 where f_o and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 4. Multiple Feedback Bandpass Filter

PACKAGE DIMENSIONS

TSOP-5 CASE 483-02 ISSUE H

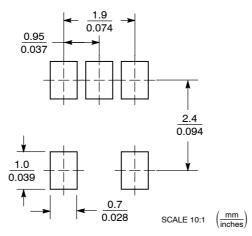


NOTES:

- DIMENSIONING AND TOLERANCING PER
 ASME V14 5M 1004
- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
- 5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS					
DIM	MIN	MIN MAX				
Α	3.00	BSC				
В	1.50	BSC				
C	0.90	1.10				
D	0.25	0.50				
G	0.95	0.95 BSC				
Н	0.01	0.10				
J	0.10	0.26				
K	0.20	0.60				
L	1.25	1.55				
М	0 °	10 °				
S	2.50 3.00					

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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